

Breakover diodes

BR211SM series

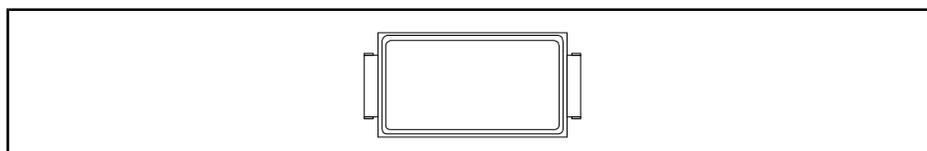
GENERAL DESCRIPTION

A range of bidirectional, breakover diodes in a two terminal, surface mounting, plastic envelope. These devices feature controlled breakover voltage and high holding current together with high peak current handling capability. Typical application is transient overvoltage protection in telecommunications equipment.

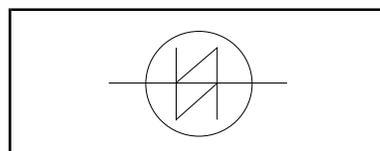
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
$V_{(BO)}$	BR211SM-140 to BR211SM-280 Breakover voltage	140	280	V
I_H	Holding current	150	-	mA
I_{TSM}	Non-repetitive peak current	-	40	A

OUTLINE - SOD106



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_D	Continuous voltage		-	75% of $V_{(BO)typ}$	V
I_{TSM1}	Non repetitive peak current	10/320 μ s impulse equivalent to 10/700 μ s, 1.6 kV voltage impulse (CCITT K17)	-	40	A
I_{TSM2}	Non repetitive on-state current	half sine wave; t = 10 ms; $T_j = 70^\circ\text{C}$ prior to surge	-	15	A
I^2t	I^2t for fusing	$t_p = 10$ ms	-	1.1	A ² s
dl_T/dt	Rate of rise of on-state current after $V_{(BO)}$ turn-on	$t_p = 10$ μ s	-	50	A/ μ s
P_{tot}	Continuous dissipation	$T_a = 25^\circ\text{C}$	-	1.2	W
P_{TM}	Peak dissipation	$t_p = 1$ ms; $T_a = 25^\circ\text{C}$	-	50	W
T_{stg}	Storage temperature		- 40	150	$^\circ\text{C}$
T_a	Operating ambient temperature	off-state	-	70	$^\circ\text{C}$
T_{vj}	Overload junction temperature	on-state	-	150	$^\circ\text{C}$

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-sp}$	Thermal resistance junction to solder point		-	-	12	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	pcb mounted; minimum footprint	-	100	-	K/W
$Z_{th\ j-a}$	Thermal impedance junction to ambient	$t_p = 1$ ms	-	2.62	-	K/W

Breakover diodes

BR211SM series

STATIC CHARACTERISTICS

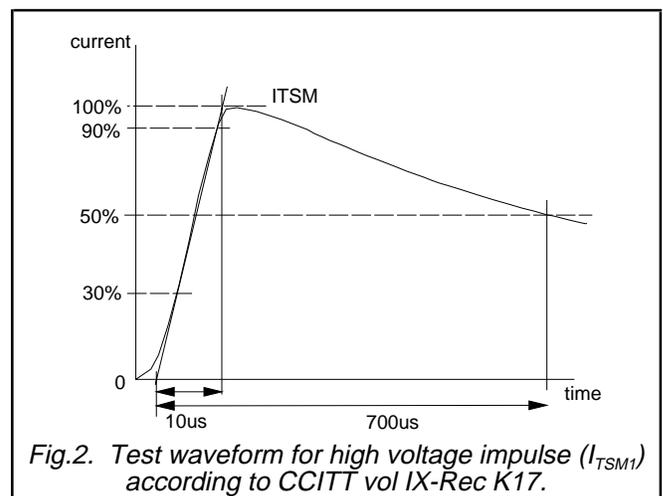
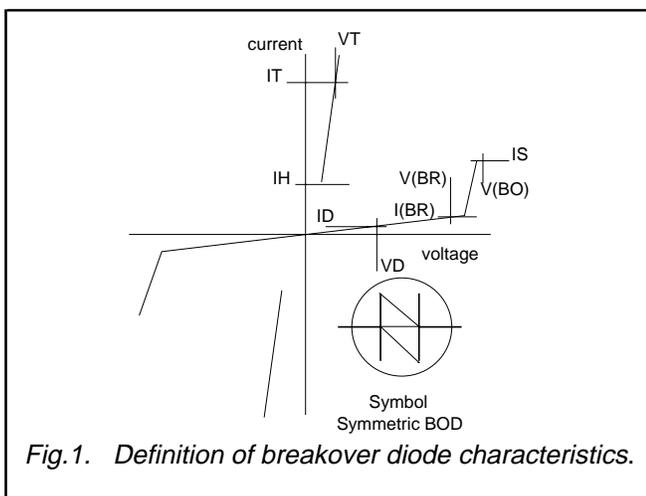
$T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{TM}^1 $V_{(BR)}$ $V_{(BO)}$	On-state voltage Avalanche voltage (min) Breakover voltage (max)	$I_{TM} = 2\text{ A}$ $I_{(BR)} = 10\text{ mA}$ $I \leq I_S, t_p = 100\text{ }\mu\text{s}$ BR211SM-140 BR211SM-160 BR211SM-180 BR211SM-200 BR211SM-220 BR211SM-240 BR211SM-260 BR211SM-280	-	-	2.5	V
$S_{(pr)}$ I_H^2	Temperature coefficient of $V_{(BR)}$ Holding current	$T_j = 25\text{ }^\circ\text{C}$ $T_j = 70\text{ }^\circ\text{C}$	-	+0.1	-	%/K mA
I_S^3 I_D^4	Switching current Off-state current	$t_p = 100\text{ }\mu\text{s}$ $V_D = 85\% V_{(BR)min}, T_j = 70\text{ }^\circ\text{C}$	10	200	1000	mA μA

DYNAMIC CHARACTERISTICS

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV_D/dt	Linear rate of rise of off-state voltage that will not trigger any device	$V_{(DM)} = 85\% V_{(BR)min}, T_j = 70\text{ }^\circ\text{C}$	-	-	2000	V/ μs
C_j	Off-state capacitance	$V_D = 0\text{ V}; f = 1\text{ kHz to } 1\text{ MHz}$	-	-	100	pF



- 1 Measured under pulsed conditions to avoid excessive dissipation
- 2 The minimum current at which the diode will remain in the on-state
- 3 The avalanche current required to switch the diode to the on-state
- 4 Measured at maximum recommended continuous voltage. Relative humidity < 65%.

Breakover diodes

BR211SM series

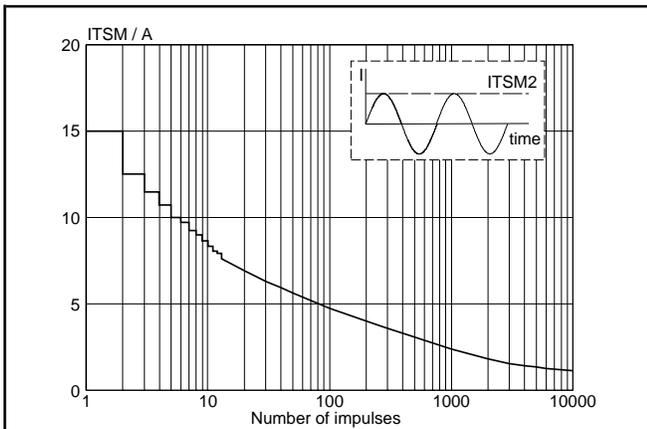


Fig.3. Maximum permissible non-repetitive on-state current based on sinusoidal currents; $f = 50$ Hz; device triggered at the start of each pulse; $T_j = 70^\circ\text{C}$ prior to surge.

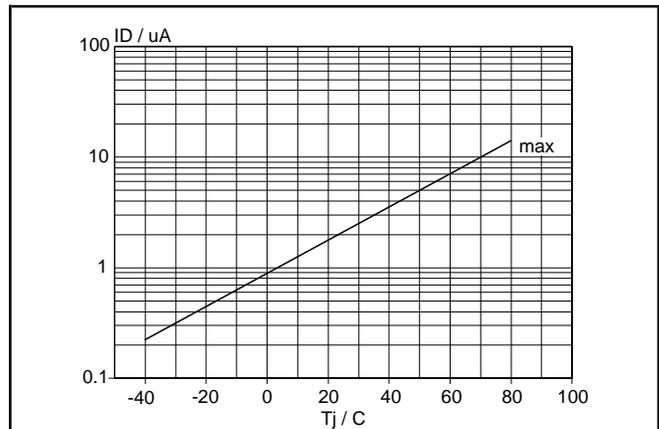


Fig.6. Maximum off-state current as a function of temperature.

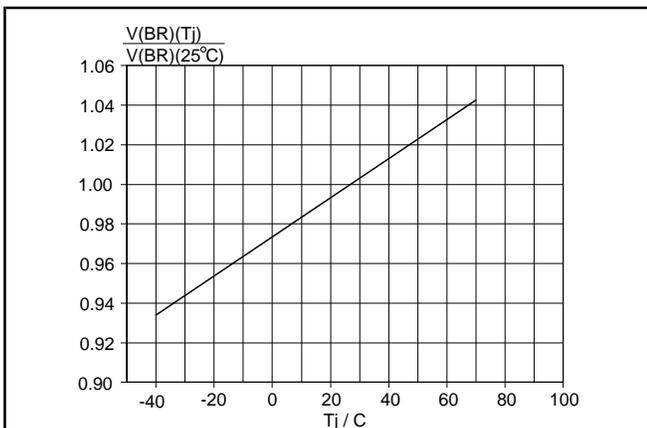


Fig.4. Normalised avalanche breakdown voltage $V_{(BR)}$ and $V_{(BO)}$ as a function of temperature.

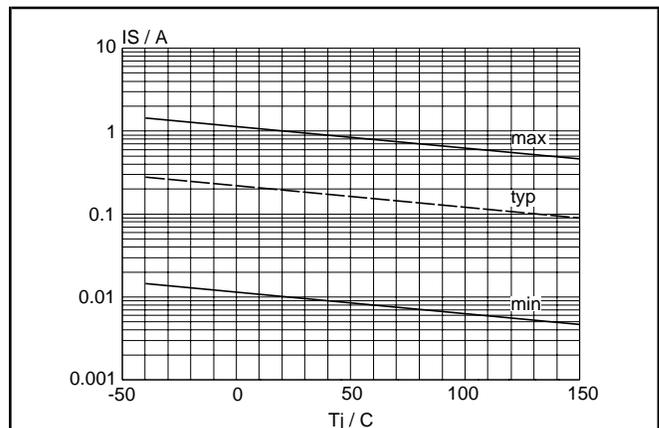


Fig.7. Switching current as a function of junction temperature.

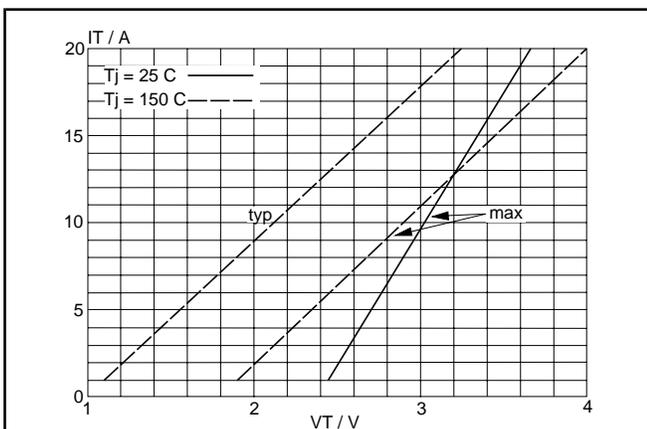


Fig.5. On-state current as a function of on-state voltage; $t_p = 200 \mu\text{s}$ to avoid excessive dissipation.

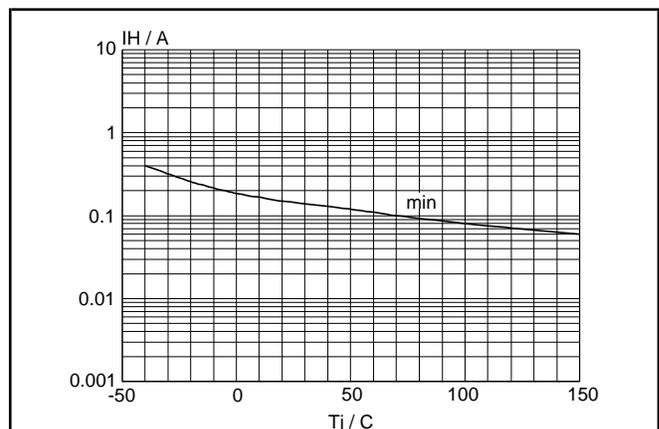
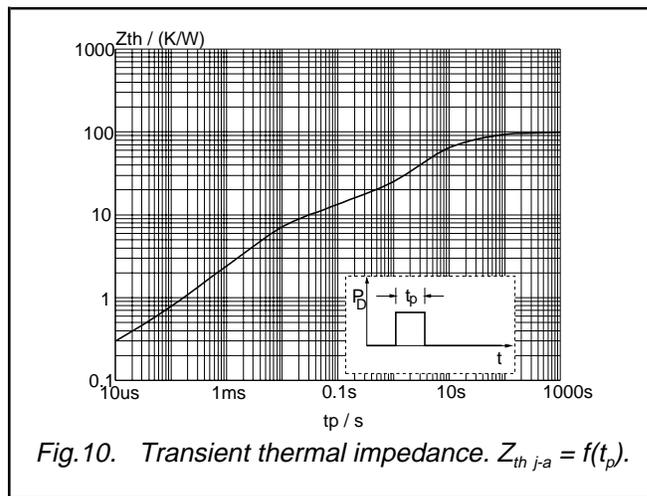
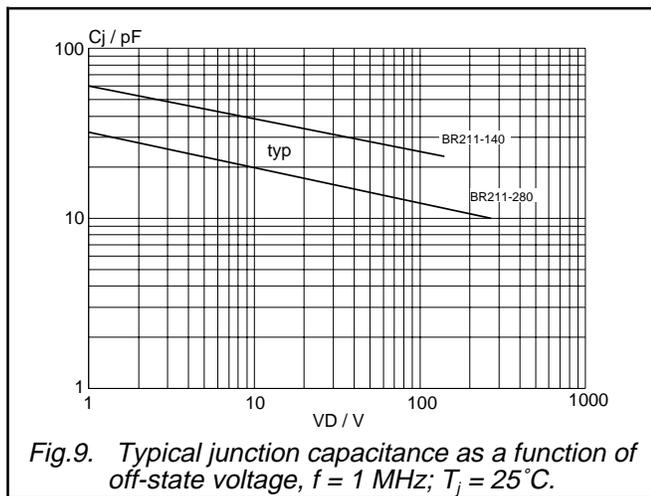


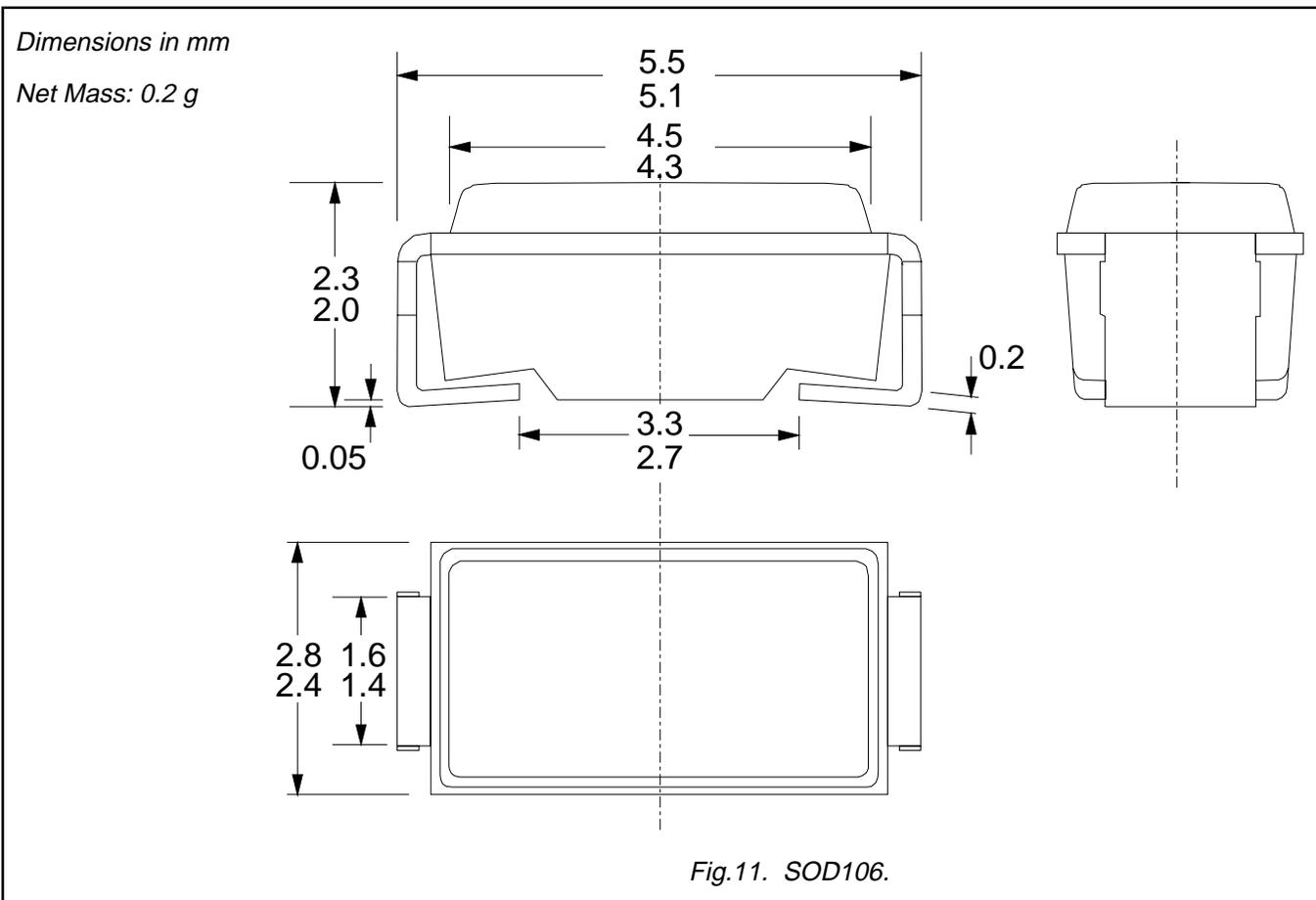
Fig.8. Minimum holding current as a function of temperature.

Breakover diodes

BR211SM series



MECHANICAL DATA



Notes

1. For mounting and soldering instructions refer to publication SC18 "SMD Footprint Design and Soldering Guidelines". Order code:9397 750 00505.

Breakover diodes

BR211SM series

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
© Philips Electronics N.V. 1996	
All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.	
The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.